NSN 5961-01-349-0226

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View Online at https://aerobasegroup.com/nsn/5961-01-349-0226 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.250 inches **Overall Width:** Between 0.990 inches and 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 850.0 collector-to-emitter substaining voltage, with specified circuit between base and emitter and 400.0 collector to emitter voltage/static/base open and 9.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 12.0 static forward current transfer ratio, common-emitter and 60.0 small-signal short-circuit forward current transfer ratio, common-base **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: